

MBR1635 - MBR16150

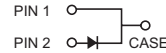
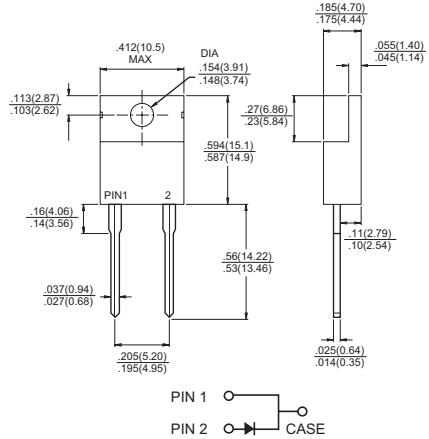
16.0 AMPS. Schottky Barrier Rectifiers

TO-220AC



Features

- ✧ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ✧ Metal silicon junction, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guarding for overvoltage protection
- ✧ High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case



Mechanical Data

- ✧ Cases: JEDEC TO-220AC molded plastic body
- ✧ Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs. max
- ✧ Weight: 0.08 ounce, 2.24 grams

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBR 1635	MBR 1645	MBR 1650	MBR 1660	MBR 1690	MBR 16100	MBR 16150	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	150	V
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	105	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	150	V
Maximum Average Forward Rectified Current at $T_c=125^{\circ}C$	$I_{(AV)}$	16							A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20KHz) at $T_c=125^{\circ}C$	I_{FRM}	32							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150							A
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1.0		0.5					A
Maximum Instantaneous Forward Voltage at: (Note 2) $I_F=16A, T_c=25^{\circ}C$ $I_F=16A, T_c=125^{\circ}C$	V_F	0.63 0.57		0.75 0.65		0.85 0.75		0.95 0.92	V
Maximum Instantaneous Reverse Current @ $T_c=25^{\circ}C$ at Rated DC Blocking Voltage (Note 2) @ $T_c=125^{\circ}C$	I_R	0.5 15		0.5 10		0.3 7.5		0.1 5	mA mA
Voltage Rate of Change (Rated V_R)	dV/dt	10,000							V/ μ S
Typical Junction Capacitance	C_j	500							pF
Maximum Typical Thermal Resistance(Note 3)	$R_{\theta JC}$	3.0							$^{\circ}C/W$
Operating Junction Temperature Range	T_J	-65 to +150							$^{\circ}C$
Storage Temperature Range	T_{STG}	-65 to +175							$^{\circ}C$

- Notes:
1. 2.0 μ s Pulse Width, $f=1.0$ KHz
 2. Pulse Test: 300 μ s Pulse Width, 1% Duty Cycle
 3. Thermal Resistance from Junction to Case Per Leg with Heatsink Size of 2" x 3"x 0.25" Al-Plate.

RATINGS AND CHARACTERISTIC CURVES (MBR1635 THRU MBR16150)

FIG.1- FORWARD CURRENT DERATING CURVE

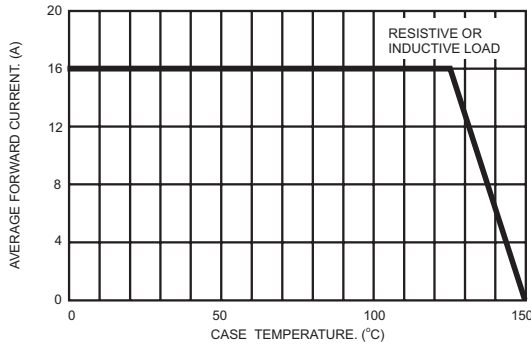


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

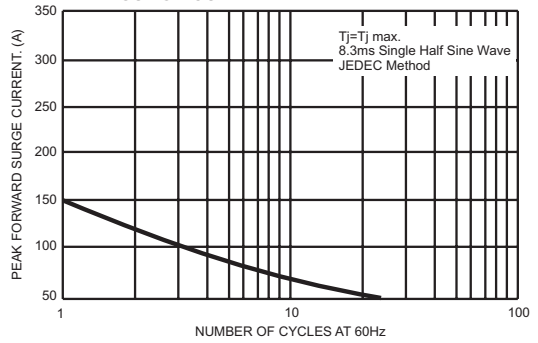


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

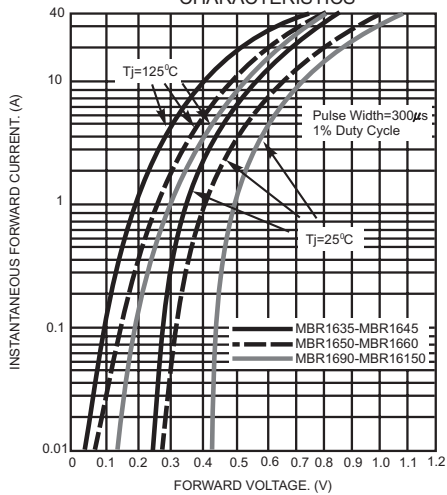


FIG.4- TYPICAL REVERSE CHARACTERISTICS

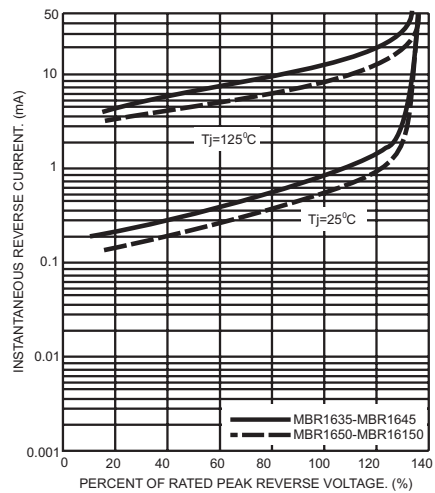


FIG.5- TYPICAL JUNCTION CAPACITANCE

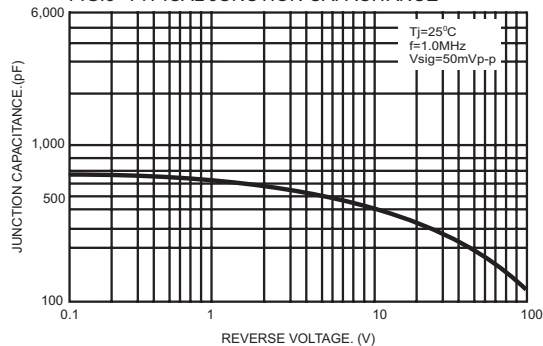


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS

